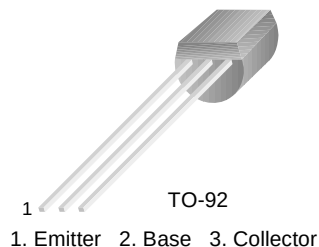


PN3642

PN3642

NPN General Purpose Amplifier

- This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300mA.



Absolute Maximum Ratings* $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	45	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	5.0	V
I_C	Collector Current - Continuous	500	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- These ratings are based on a maximum junction temperature of 150 degrees C.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Electrical Characteristics $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage *	$I_C = 10\text{mA}, I_B = 0$	45		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10\mu\text{A}, I_E = 0$	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10\mu\text{A}, I_C = 0$	5.0		V
I_{CES}	Collector Cut-off Current	$V_{CB} = 50\text{V}, I_E = 0$ $V_{CB} = 50\text{V}, I_E = 0, T_A = 65^\circ\text{C}$		50 1.0	nA μA
On Characteristics					
h_{FE}	DC Current Gain	$V_{CE} = 10\text{V}, I_C = 150\text{mA}$ $V_{CE} = 10\text{V}, I_C = 500\text{mA}$	40 15	120	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 150\text{mA}, I_B = 15\text{mA}$		0.22	V
Small Signal Characteristics					
C_{ob}	Output Capacitance	$V_{CB} = 10\text{V}, f = 140\text{KHz}$		8.0	pF
h_{fe}	Small Signal Current Gain	$I_C = 50\text{mA}, V_{CE} = 5.0\text{V}, f = 100\text{MHz}$	1.5		
G_{pe}	Amplifier Power Gain	$V_{CE} = 15\text{V}, I_C = 0, R_G = 140\Omega$ $f = 30\text{MHz}, R_L = 260\Omega$	10		dB
η	Collector Efficiency	$V_{CE} = 15\text{V}, I_C = 0, R_G = 140\Omega$ $f = 30\text{MHz}, R_L = 260\Omega$	60		%

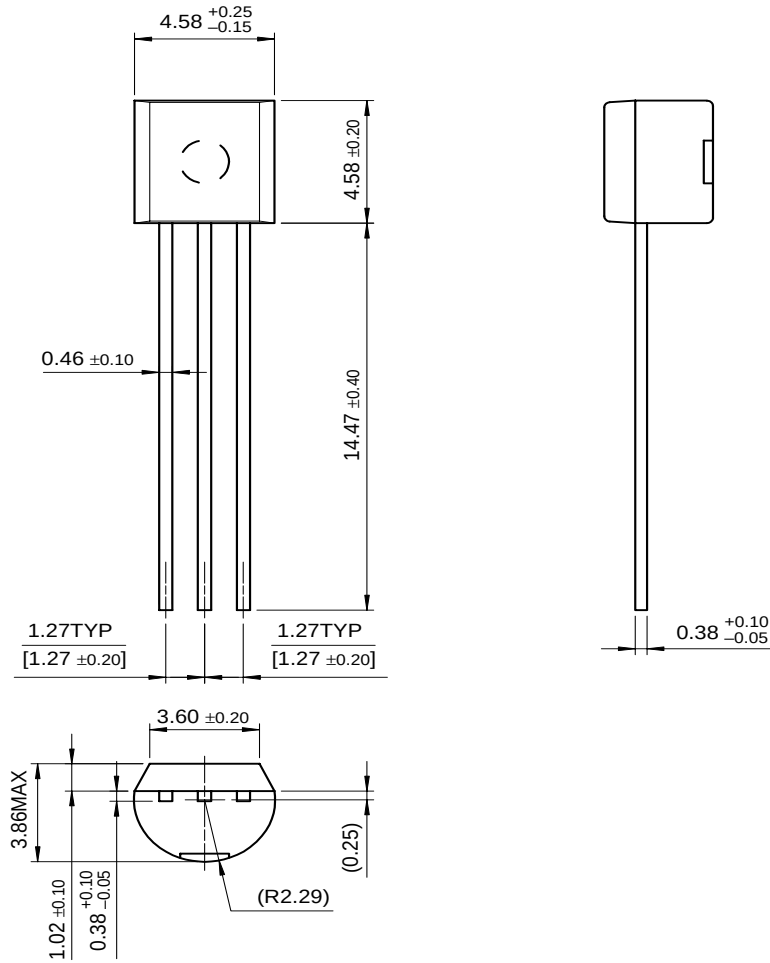
* Pulse Test: Pulse Width $\leq 300\text{ms}$, Duty Cycle $\leq 2.0\%$

Thermal Characteristics $T_A=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Units
P_D	Total Device Dissipation Derate above 25°C	625 5.0	mW $\text{mW}/^{\circ}\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	$^{\circ}\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	$^{\circ}\text{C}/\text{W}$

Package Dimensions

TO-92



Dimensions in Millimeters

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